## Onsemi

## **ECOSPARK<sup>®</sup> II, Ignition IGBT**

#### 300 mJ, 500 V, N-Channel Ignition IGBT

### FGD3050G2

#### Features

- SCIS Energy = 300 mJ at  $T_J = 25^{\circ}C$
- Logic Level Gate Drive
- AEC-Q101 Qualified and PPAP Capable
- This Device is Pb-Free, Halid Free and is RoHS Compliant

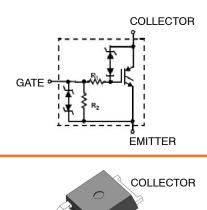
#### Applications

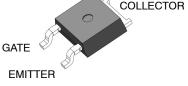
- Automotive Ignition Coil Driver Circuits
- Coil on Plug Application

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
BV <sub>CER</sub>	Collector to Emitter Breakdown Voltage (I <sub>C</sub> = 1 mA)	500	V
BV <sub>ECS</sub>	Emitter to Collector Voltage – Reverse Battery Condition ( $I_C = 10 \text{ mA}$ )	20	V
E <sub>SCIS25</sub>	$I_{SCIS}$ = 14.2 A, L = 3.0 mHy, $R_{GE}$ = 1 k $\Omega$ $T_{C}$ = 25°C	300	mJ
E <sub>SCIS150</sub>	$I_{SCIS}$ = 11.0 A, L = 3.0 mHy, R <sub>GE</sub> = 1 kΩ T <sub>C</sub> = 150°C	180	mJ
I <sub>C25</sub>	Collector Current Continuous at $V_{GE}$ = 5.0 V, T <sub>C</sub> = 25°C	32	A
I <sub>C110</sub>	Collector Current Continuous at V <sub>GE</sub> = 5.0 V, T <sub>C</sub> = 110°C	27	A
$V_{\text{GEM}}$	Gate to Emitter Voltage Continuous	±10	V
PD	Power Dissipation Total, $T_C = 25^{\circ}C$	150	W
	Power Dissipation Derating, $T_C > 25^{\circ}C$	1.1	W/°C
TJ	Operating Junction Temperature Range	-40 to +175	°C
T <sub>STG</sub>	Storage Junction Temperature Range	-40 to +175	°C
ΤL	T <sub>L</sub> Max. Lead Temperature for Soldering (Leads at 1.6 mm from case for 10 s)		°C
Т <sub>РКG</sub>	T <sub>PKG</sub> Max. Lead Temperature for Soldering (Package Body for 10 s)		°C
ESD	Electrostatic Discharge Voltage at 100 pF, 1500 $\Omega$	4	kV

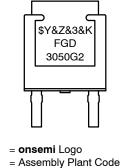
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.





DPAK3 (TO-252 3 LD) CASE 369AS

#### MARKING DIAGRAM



&Z &3 = 3-Digit Date Code

= 2-Digits Lot Run Traceability Code

&K FGD3050G2 = Specific Device Code

\$Y

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 6 of this data sheet.

#### THERMAL CHARACTERISTICS

Symbol	Characteristic	Max	Units
$R_{\theta JC}$	Thermal Resistance Junction to Case	0.9	°C/W

#### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise specified)

Current Fall Time-Inductive

t<sub>fL</sub>

			• •				
Symbol	Parameter	Test Conditions		Min	Тур.	Max.	Units
OFF CHARA	ACTERISTICS	-					
BV <sub>CER</sub>	Collector to Emitter Breakdown Voltage	$I_{CE}$ = 2 mA, $V_{GE}$ = 0 V, R <sub>GE</sub> = 1 kΩ, T <sub>J</sub> = -40 to 150°C		470	-	530	V
BV <sub>CES</sub>	Collector to Emitter Breakdown Voltage	I <sub>CE</sub> = 10 mA, V <sub>GE</sub> = 0 V, R <sub>GE</sub> = 0 Ω, T <sub>J</sub> = −40 to 150°C		495	-	555	V
BV <sub>ECS</sub>	Emitter to Collector Breakdown Voltage	I <sub>CE</sub> = -75 mA, V <sub>GE</sub> = 0 V, T <sub>J</sub> = 25°C		20	-	-	V
BV <sub>GES</sub>	Gate to Emitter Breakdown Voltage	I <sub>GES</sub> = ±5 mA		±12	±14	-	V
I <sub>CER</sub>	Collector to Emitter Leakage Current	V <sub>CE</sub> = 250 V R <sub>GE</sub> = 1 kΩ	$T_J = 25^{\circ}C$	-	-	25	μA
			T <sub>J</sub> = 150°C	-	-	1	mA
I <sub>ECS</sub>	Emitter to Collector Leakage Current	V <sub>EC</sub> = 15 V	$T_J = 25^{\circ}C$	-	-	1	mA
			T <sub>J</sub> = 150°C	-	-	40	
R <sub>1</sub>	Series Gate Resistance			-	111	-	Ω
R <sub>2</sub>	Gate to Emitter Resistance			10	-	30	kΩ
ON CHARAG	CTERISTICS						
V <sub>CE(SAT)</sub>	Collector to Emitter Saturation Voltage	$I_{CE}$ = 6 A, $V_{GE}$ = 4 V, $T_{J}$ = 25°C		-	1.1	1.2	V
$V_{CE(SAT)}$	Collector to Emitter Saturation Voltage	$I_{CE}$ = 10 A, $V_{GE}$ = 4.5 V, $T_{J}$ = 150°C		-	1.3	1.45	V
$V_{CE(SAT)}$	Collector to Emitter Saturation Voltage	$I_{CE}$ = 15 A, $V_{GE}$ = 4.5 V, $T_{J}$ = 150°C		-	1.6	1.75	V
OYNAMIC C	HARACTERISTICS						
Q <sub>G(ON)</sub>	Gate Charge	$I_{CE}$ = 10 A, $V_{CE}$ = 12 V, $V_{GE}$ = 5 V		-	22	-	nC
V <sub>GE(TH)</sub>	Gate to Emitter Threshold Voltage	I <sub>CE</sub> = 1 mA V <sub>CE</sub> = V <sub>GE</sub>	$T_J = 25^{\circ}C$	1.3	1.6	2.2	V
. /			T <sub>J</sub> = 150°C	0.75	1.1	1.8	
V <sub>GEP</sub>	Gate to Emitter Plateau Voltage	V <sub>CE</sub> = 12 V, I <sub>CE</sub> = 10 A		-	2.7	-	V
SWITCHING	CHARACTERISTICS						
t <sub>d(ON)R</sub>	Current Turn–On Delay Time–Resistive	$\begin{array}{l} V_{CE} = 14 \text{ V}, \text{ R}_{L} = 1 \ \Omega, \\ V_{GE} = 5 \text{ V}, \text{ R}_{G} = 1 \ \text{k}\Omega, \end{array}$		-	0.9	4	μs
t <sub>rR</sub>	Current Rise Time-Resistive	1		-	1.6	7	μs
t <sub>d(OFF)</sub> L	Current Turn-Off Delay Time-Inductive	$V_{CE}$ = 300 V, L = 2 mH, $V_{GE}$ = 5 V, $R_G$ = 1 k $\Omega$ ,		-	5.4	15	μs
	1	1			<u> </u>		1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

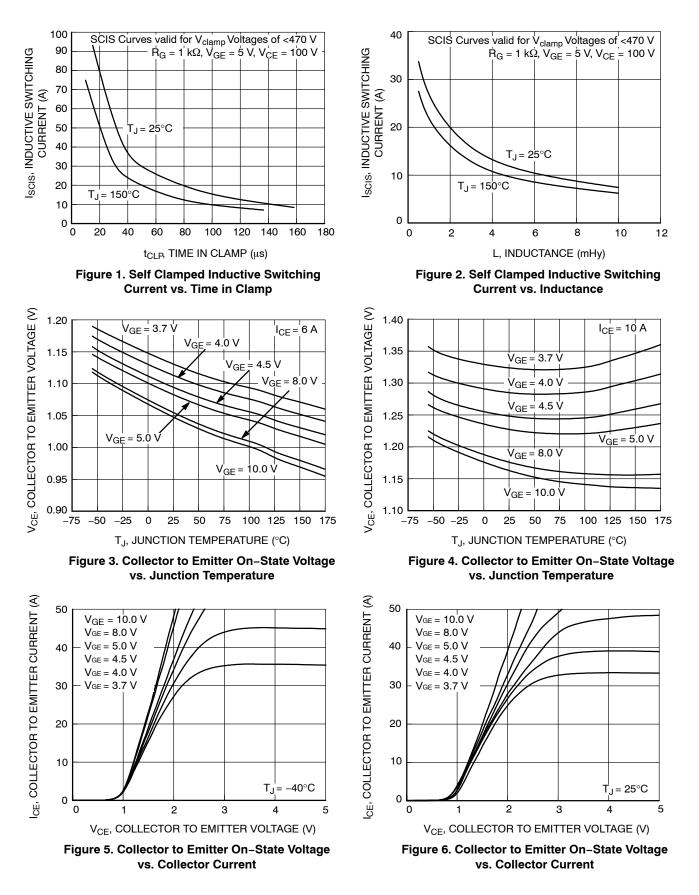
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1.4

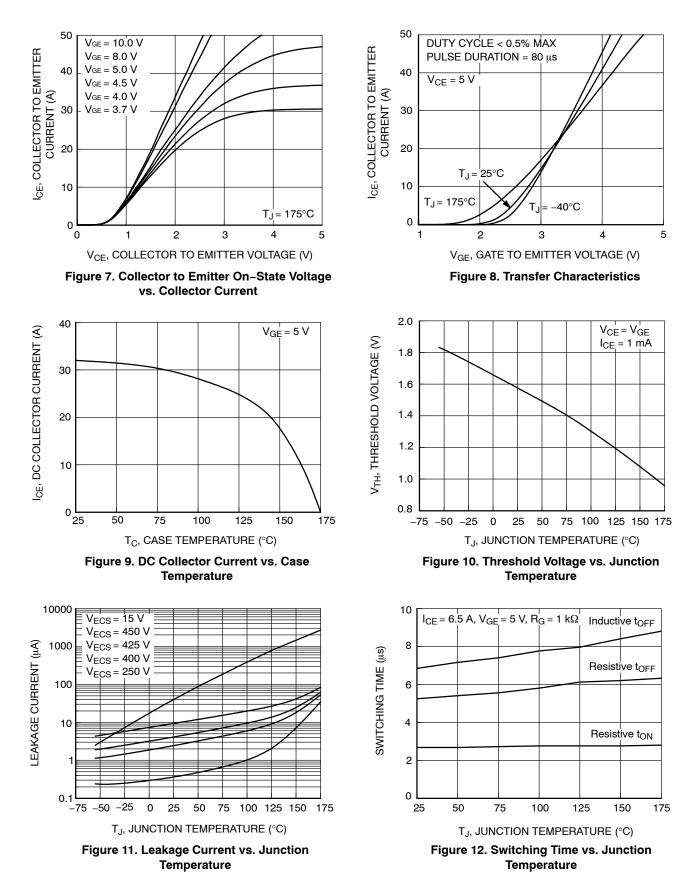
15

μs

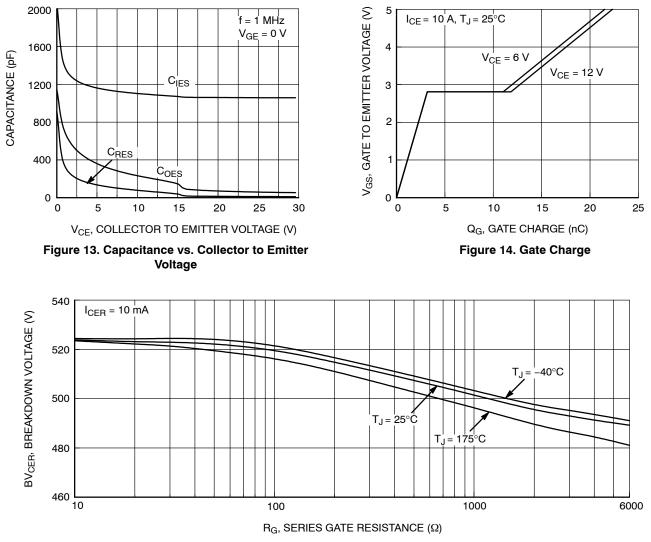
#### **TYPICAL CHARACTERISTICS**



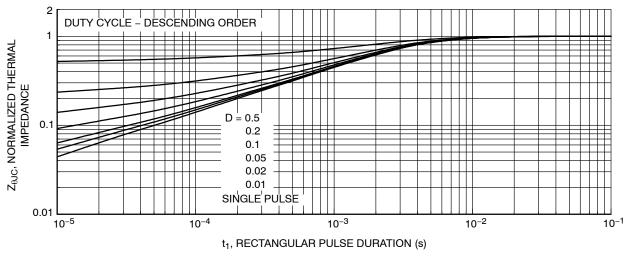
#### TYPICAL CHARACTERISTICS (continued)



#### TYPICAL CHARACTERISTICS (continued)



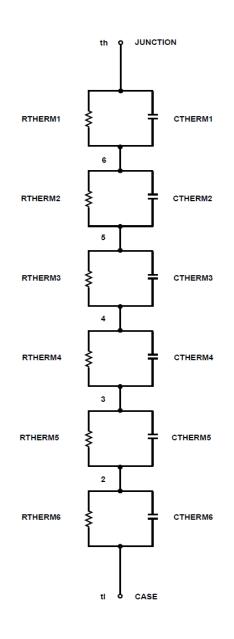






#### SPICE THERMAL MODEL

CTHERM1	tł	n 6 5.7337E-05
CTHERM2	6	5 5.3736E-03
CTHERM3	5	4 1.1141E-03
CTHERM4	4	3 2.8690E-04
CTHERM5	3	2 7.4429E-04
CTHERM6	2	tl 3.7019E-03
RTHERM1	tł	n 6 6.6403E-03
RTHERM1 RTHERM2	01	n 6 6.6403E-03 5 5.8449E-01
	01	
RTHERM2	6	5 5.8449E-01
RTHERM2 RTHERM3	6 5	5 5.8449E-01 4 5.3930E-02



#### PACKAGE MARKING AND ORDERING INFORMATION

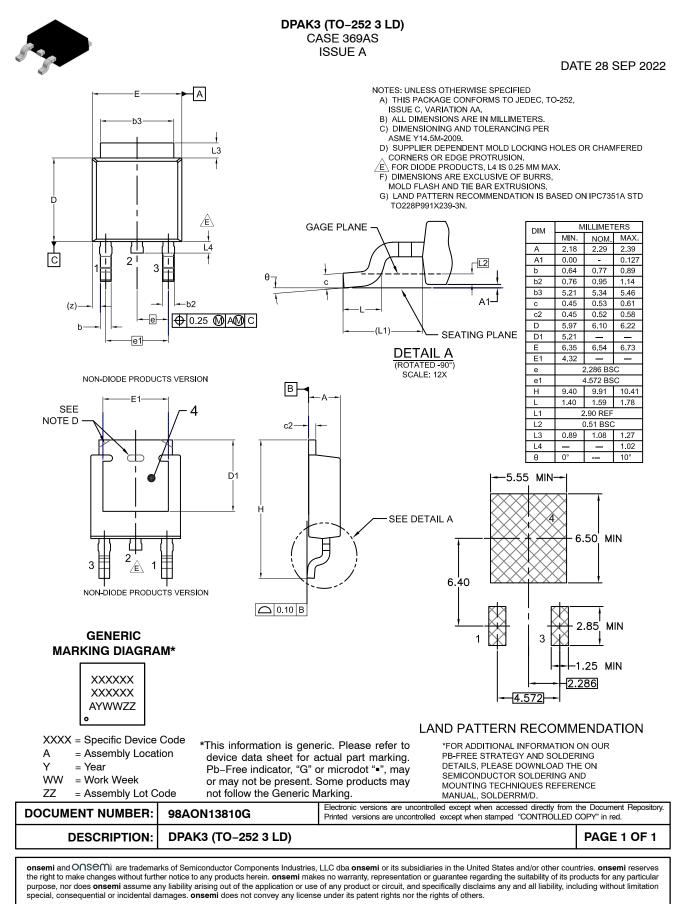
Device	Device Marking	Package	Shipping <sup>†</sup>
FGD3050G2	FGD3050G2	DPAK3 (TO-252 3 LD) (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

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#### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

# Onsemi



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